



#### 40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C (Note 9)
40V	$7.6 \text{m}\Omega$ @ V <sub>GS</sub> = 10V	100A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power managements
- DC-DC converters
- Motor controls

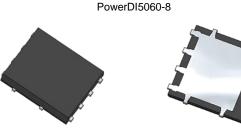
### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications</li>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4007SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

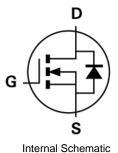
https://www.diodes.com/quality/product-definitions/

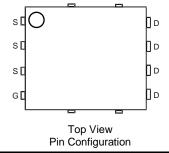
#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.097 grams (Approximate)









## **Ordering Information** (Note 4)

Top View

Dord Nillian how	Dookono	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4007SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	

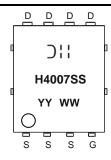
Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

Pin1

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**





# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	15.7 13.1	А
Continuous Drain Current (Note 6)	$T_{C} = +25^{\circ}C$ (Note 9) $T_{C} = +100^{\circ}C$	lo	100 77	А
Maximum Continuous Body Diode Forward Current (N	Note 6)	Is	100	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	120	Α
Avalanche Current, L = 0.3mH		las	20	Α
Avalanche Energy, L = 0.3mH		Eas	60	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	53	°C/W	
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	136	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		BVDSS	40	_	_	V	$V_{GS} = 0V$ , $I_{D} = 1mA$
Zero Gate Voltage Drain Current	_	IDSS	l	_	1	μΑ	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V
	(Note 8)	I <sub>DSS</sub>		_	100	μΑ	$V_{DS} = 32V, V_{GS} = 0V, T_{J} = +125^{\circ}C$
Gate-Source Leakage		Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage		$V_{GS(TH)}$	2	_	4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance		RDS(ON)		4.9	7.6	mΩ	$V_{GS} = 10V, I_{D} = 20A$
Diode Forward Voltage		VsD	l	_	1.2	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 20A
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance		Ciss	1	2,082	_		V 05V V 0V
Output Capacitance Reverse Transfer Capacitance		Coss	l	790	_	pF	$V_{DS} = 25V$ , $V_{GS} = 0V$ , $f = 1MHz$
		Crss	-	113	_		
Gate Resistance		$R_g$	0.1	0.46	1.4	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge		Qg	l	41.9	_		
Gate-Source Charge		$Q_gs$	l	10	_	nC	$V_{DS} = 30V$ , $I_{D} = 20A$ , $V_{GS} = 10V$
Gate-Drain Charge		Q <sub>gd</sub>	_	11.5	_		
Turn-On Delay Time		tD(ON)	_	7	_		
Turn-On Rise Time		t <sub>R</sub>	_	11.5	_	ns	$V_{DD} = 30V$ , $V_{GS} = 10V$ , $I_D = 20A$ , $R_G = 3\Omega$
Turn-Off Delay Time		tD(OFF)	_	15.6	_		
Turn-Off Fall Time		tF	_	8.8	_		
Body Diode Reverse Recovery Time		trr	_	29.9	_	ns	I= 204 di/dt 1004/up
Body Diode Reverse Recovery Charge		Q <sub>RR</sub>	_	23	_	nC	IF = 20A, di/dt = 100A/μs

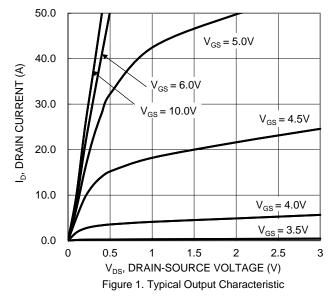
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.

Guaranteed by design. Not subject to product testing.
 Package limited.







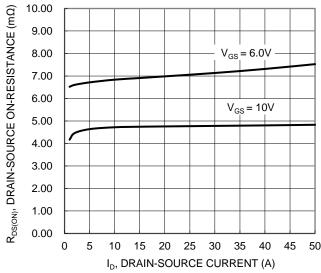


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

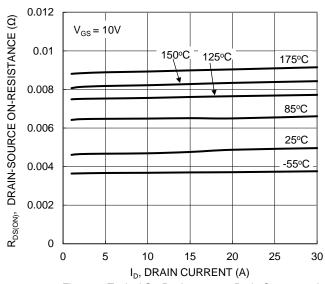
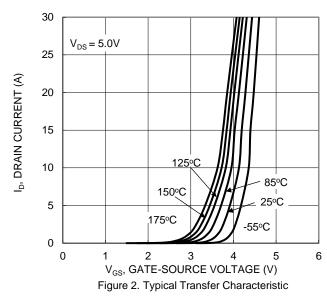


Figure 5. Typical On-Resistance vs. Drain Current and Temperature



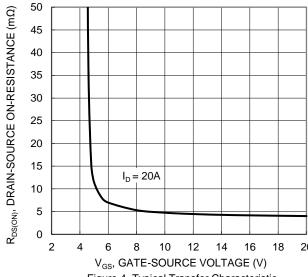


Figure 4. Typical Transfer Characteristic

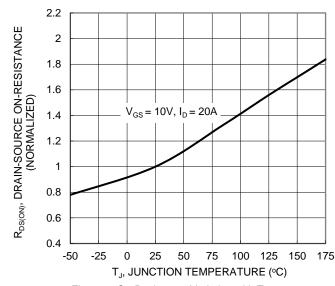


Figure 6. On-Resistance Variation with Temperature





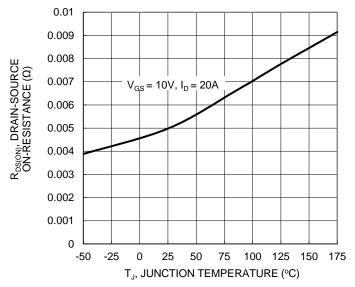
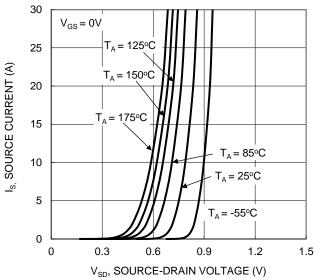
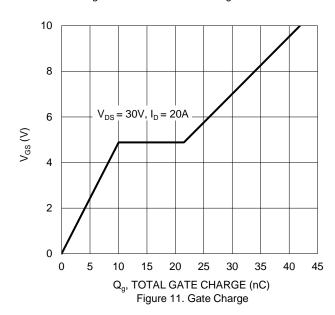


Figure 7. On-Resistance Variation with Temperature



V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current



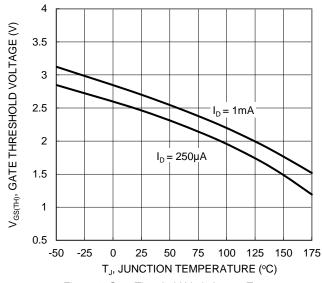
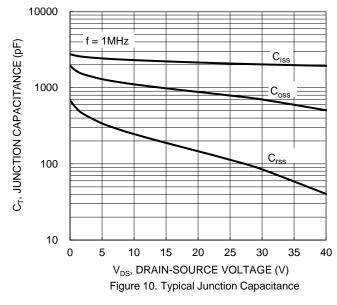
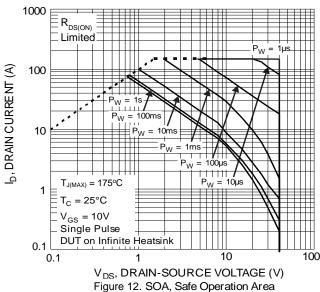


Figure 8. Gate Threshold Variation vs. Temperature







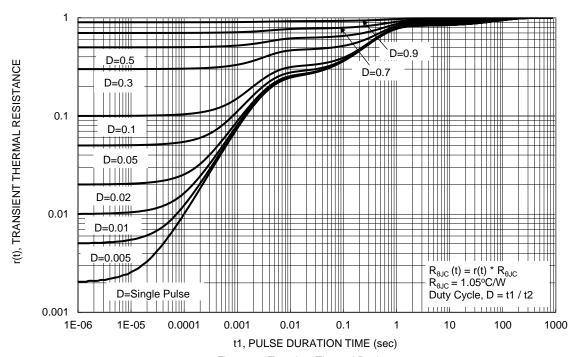


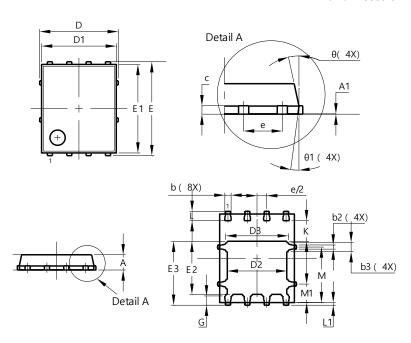
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

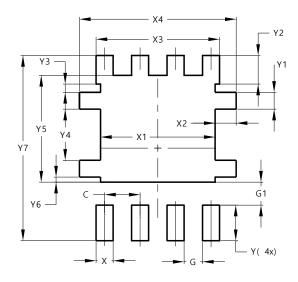


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	3.70 4.10			
D3	3.90				
Е	(	6.15 BSC	;		
E1	5.60 6.00		5.80		
E2	3.28	3.68	3.48		
E3			4.19		
е	•	1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	_	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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